

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Applicants: KIM, Hyun-Jae and KANG, Myung-Koo  
Assignee: SAMSUNG ELECTRONICS CO., LTD.  
Title: METHOD OF POLYCRYSTALLIZATION, METHOD OF MANUFACTURING POLYSILICON THIN FILM TRANSISTOR, AND LASER IRRADIATION DEVICE THEREFOR  
Application No.: 10/532,459 Filing Date: 11/02/2005  
Examiner: BOOTH, Richard A. Group Art Unit: 2812  
Docket No.: AB-1432 US Confirmation No.: 1783

San Jose, California  
June 4, 2007

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)**

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying Form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed with the exception of any U.S. Patents and U.S. Patent Publications. The documents were first cited in an Office Action dated March 30, 2007 by the Chinese Patent Office in corresponding Chinese Patent Application No. 200380101946.7.

Citation of these documents shall not be construed as:

1. an admission that the documents are necessarily prior art with respect to the instant invention;
2. a representation that a search has been made, other than as described above; or
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No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

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Respectfully submitted,



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U.S. Department of Commerce, Patent and Trademark Office			Atty. Docket No.		Application No.			
			AB-1432 US		10/532,459			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)			Applicant(s) KIM, Hyun-Jae and KANG, Myung-Koo					
			Filing Date		Group			
			11/02/2005		2812			
U.S. Patent Documents								
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
	AA							
	AB							
	AC							
	AD							
	AE							
	AF							
	AG							
	AH							
	AI							
	AJ							
	AK							
Foreign Patent Documents								
							Translation	
							Yes	No
	AL	CN 1304548 A	07/18/2001	China				X
	AM							
	AN							
	AO							
	AP							
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)								
	AQ	English Language Abstract, Publication No. CN 1304548, 07/18/2001, 1 p.						
	AR							
	AS							
Examiner		Date Considered						
<p><b>*EXAMINER:</b> Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.</p>								